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<u>IN THE UNITED STATES PATENT AND TRADEMARK OFFICE</u>

Applicant: Cyril Cabral Jr., et al.

Docket: 16695

Patent No.: 6,943,097

Dated: March 06, 2006

Issued: September 13, 2005

For: ATOMIC LAYER DEPOSITION OF

METALLIC CONTACTS, GATES AND

DIFFUSION BARRIERS

Certificate

MAR 1 5 2006

of Correction

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

REQUEST FOR CERTIFICATE OF CORRECTION

Sir:

It appears that errors have been introduced in the course of printing the Patent issued in the above application, and it is respectfully requested that the Commissioner issue a Certificate of Correction in the following respects:

Column 4, Line 21:

"thereof An" should read -- thereof. An --

Respectfully submitted,

Leglie S. Szivos Reg. No. 39,394

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 6,943,097

APPLICATION NO: 10/643,534

ISSUE DATE : September 13, 2005

INVENTOR(S) : Cyril Cabral Jr., et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 4, Line 21:

"thereof An" should read -- thereof. An --

MAILING ADDRESS OF SENDER:

Scully, Scott, Murphy & Presser 400 Garden City Plaza, Suite 300 Garden City, New York 11530 PATENT No. 6,943,097

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